

Titles

Investigation of Factors Affecting the Stability of Compounds formed by Isovalent Substitution in Layered Oxychalcogenides, Leading to Identification of $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{Se}_2$, $\text{Ba}_3\text{Y}_2\text{O}_5\text{Cu}_2\text{S}_2$, $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Ag}_2\text{Se}_2$ and $\text{Ba}_3\text{In}_2\text{O}_5\text{Ag}_2\text{Se}_2$

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Abstract

Four novel compositions containing chalcogenide layers, adopting the $\text{Ba}_3\text{M}_2\text{O}_5\text{M}'_2\text{Ch}_2$ layered structure have been identified: $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{Se}_2$, $\text{Ba}_3\text{Y}_2\text{O}_5\text{Cu}_2\text{S}_2$, $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Ag}_2\text{Se}_2$ and $\text{Ba}_3\text{In}_2\text{O}_5\text{Ag}_2\text{Se}_2$. A comprehensive comparison of experimental and computational results providing the crystallographic and electronic structure of the compounds under investigation has been conducted. Materials were synthesised at 800°C under vacuum using a conventional ceramic synthesis route with combination of binary oxide and chalcogenide precursors. We report their structures determined by Rietveld refinement of X-ray powder diffraction patterns, and band gaps determined from optical measurements, which range from 1.44 eV to 3.04 eV. Through computational modelling we can also present detailed band structures and propose that based on their predicted transport properties that $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Ag}_2\text{Se}_2$ has potential as visible light photocatalyst and that $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{Se}_2$ is of interest as a p-type transparent conductor. These four novel compounds are part of a larger series of sixteen compounds adopting the $\text{Ba}_3\text{M}_2\text{O}_5\text{M}'_2\text{Ch}_2$ structure that we have considered, of which approximately half are stable and can be synthesized. Analysis of the compounds that cannot be synthesized from this group allows us to identify why compounds containing either $M = \text{La}$, or silver sulfide chalcogenide layers, cannot be formed in this structure type.

Keywords: $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{Se}_2$; $\text{Ba}_3\text{Y}_2\text{O}_5\text{Cu}_2\text{S}_2$; $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Ag}_2\text{Se}_2$; $\text{Ba}_3\text{In}_2\text{O}_5\text{Ag}_2\text{Se}_2$; Crystal structure; Optical band gap; mixed anion; oxychalcogenide; oxysulfide; oxyselenide

Introduction

The mixed-anion layered material $\text{Sr}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{S}_2$ has been identified as a promising p-type transparent conductor, having an unusually high hole mobility,^{1, 2} which subsequently prompted a computational search for further p-type conductors adopting this structure.³ Isostructural oxysulfides, $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{S}_2$ and $\text{Ba}_3\text{In}_2\text{O}_5\text{Cu}_2\text{S}_2$, have been found to be photocatalysts,⁴ in common with other layered oxysulfides.^{5, 6} The 32522 structure of $\text{Sr}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{S}_2$ – the designation derived from the ratio of the ions – adopted by these compounds is part of a broader class of oxychalcogenides with isostructural copper or silver chalcogenide *anti-litharge* layers, separated by oxide layers with varying thickness and co-ordination, often adopting a fragment of the perovskite structure.⁷⁻⁹ The separation of the ‘heavy’ chalcogenide layers by the ‘light’ oxide layers in these materials creates a quantum well leading to hole transport in the chalcogenide layers combined with a large band gap,^{10, 11} resulting in the photocatalysis and p-type conducting functions observed in these materials.

Specifically, in the 32522 structure, $A_3M_2O_5M'_2X_2$, the ‘heavy’ anion layer $[M'_2X_2]^{2-}$ adopts the *anti-litharge* structure, while the oxide layer $[A_3M_2O_5]^{2+}$ adopts a triple layer fragment of the *perovskite* structure, but truncated such that the geometry of the M ion is pyramidal rather than octahedral. There is a competing and related structure type which can be formed using ions with the same formal charges, the 42622, with general formula $A_4M_2O_6M'_2X_2$, sometimes expressed as the empirical formula $AM_2O_3M'X$. In comparison to the 32522 structure, the 42622 has an additional rock-salt structured AO layer which shears and displaces the vertex sharing of the apical oxygen of the MO_5 polyhedra. Schematic unit cells for the two structures are shown in figure 1. It has been previously identified that there is a delicate balance between the stability of the 42622 or 32522 structure for a given combination of ions.¹² For example, $\text{Sr}_4\text{Ga}_2\text{O}_6\text{Cu}_2\text{S}_2$ is stable, but the 32522 equivalent is not. Replacing gallium with scandium, it is found that both structures, $\text{Sr}_4\text{Sc}_2\text{O}_6\text{Cu}_2\text{S}_2$ and $\text{Sr}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{S}_2$, can be formed. With further substitution of strontium by barium it is found that only the 32522 structure is formed, $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{S}_2$. The overall trend is that moving from smaller ions (Sr^{2+} , Ga^{3+}) to larger ions (Ba^{2+} , Sc^{3+}) leads to a preference for the 32522 structure over the 42622 structure.

A survey of the literature indicates that there are a total of 10 compounds adopting the 32522 structure, where full structural details are available. The 42622 is slightly more numerous with 14 examples known. These mixed anion compounds have been found with a range of trivalent M ions in the $[A_4M_2O_6]^{2+}$ or $[A_3M_2O_5]^{2+}$ layers, including ions of chromium, gallium, vanadium, iron, manganese, scandium, and indium. The smaller Cr^{3+} , Ga^{3+} and V^{3+} ions are only found with the 42622 structure, the larger Fe^{3+} , Mn^{3+} and Sc^{3+} have been found in both the 32522 and 42622 types,

while the largest, In^{3+} , has only been found in the 32522 structure. A structure map plotting the average $M\text{-O}$ bond length and the average $A\text{-O}$ bond length is shown in figure 1, this indicates that for a given $M\text{-O}$ bond length the 32522 structure has a larger A ion site than the 42622 structure. Therefore, the structure map indicates that novel compositions that might adopt the 32522 structure are more likely to be found in compositions containing larger A ions.

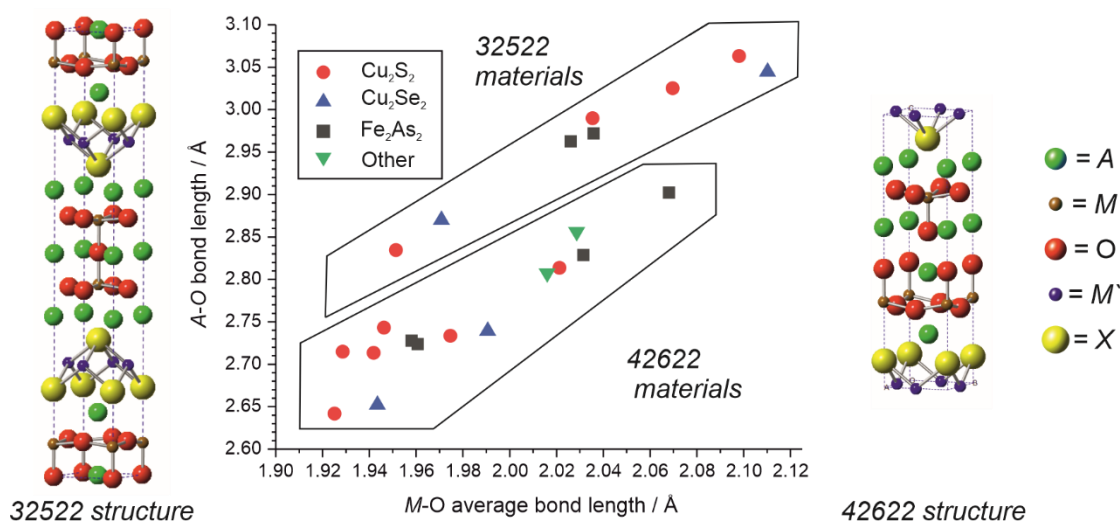


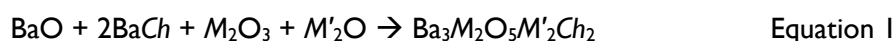
Figure 1. Structure Map of layered mixed anion phases showing adoption of either 32522 or 42622. Examples with copper sulphide heavy layers are indicated by red circles, copper selenide by blue triangles, iron arsenides by black squares, and the less common layers (iron phosphide, cobalt arsenide, nickel phosphide and nickel arsenide) by green triangles.

In this work we report on our attempt to identify new materials adopting the 32522 structure with optical and transport properties which will make them viable for p-type conducting or photocatalysis applications. In order to prevent the intra-band trapping states that would be detrimental to both these applications, this requires that the M ion must be a d^0 and d^{10} trivalent cation.¹³ Our search of this space will include the Sc^{3+} ion, and the less studied larger ions, In^{3+} , Y^{3+} and La^{3+} all combined with the largest practicable alkaline earth ion, Ba^{2+} , which based on the analysis of the structure map should favour the formation of the 32522 structure. In a systematic review we will report our attempts to combine these four oxide layers; $[\text{Ba}_3\text{Sc}_2\text{O}_5]^{2+}$, $[\text{Ba}_3\text{In}_2\text{O}_5]^{2+}$, $[\text{Ba}_3\text{Y}_2\text{O}_5]^{2+}$, and $[\text{Ba}_3\text{La}_2\text{O}_5]^{2+}$, with the four heavy anion layers; $[\text{Cu}_2\text{S}_2]^{2-}$, $[\text{Cu}_2\text{Se}_2]^{2-}$, $[\text{Ag}_2\text{S}_2]^{2-}$ and $[\text{Ag}_2\text{Se}_2]^{2-}$. This provides a matrix of 16 compounds in which to study the structural and property trends, by XRD, spectroscopy and computational modelling. Four of these sixteen are known, although one has not had a detailed structure published previously. We find that no lanthanum containing compound can be formed, nor any compound with a $[\text{Ag}_2\text{S}_2]^{2-}$ heavy layer, and we will discuss the factors behind the instability of these compositions. However, we can report $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{Se}_2$, $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Ag}_2\text{Se}_2$, $\text{Ba}_3\text{In}_2\text{O}_5\text{Ag}_2\text{Se}_2$, and $\text{Ba}_3\text{Y}_2\text{O}_5\text{Cu}_2\text{Se}_2$ as novel compounds.

Experimental Section

Solid state synthesis

Layered intergrowth compounds of the form $Ba_3M_2O_5M'Ch_2$ were targeted in 0.5 g batches by the conventional ceramic synthesis route – *i.e.* direct combination of appropriate stoichiometric ratios of binary precursors. As shown in equation 1, for our target layered compounds we combined BaO, BaCh, M_2O_3 and $M'O$ in the ratio, 1:2:1:1, where Ch = S or Se; M = Sc, In Y or La; and M' = Cu or Ag. The powders were mixed and ground together in a nitrogen-filled glove box, before being pressed into pellets using a hydraulic press with a pressure of 0.75 GPa. The pellets were placed in alumina crucibles and sealed inside a quartz tube under vacuum to form an evacuated ampoule. The samples were reacted at 800 °C for an additional 12 hours, followed by regrinding and resealing under vacuum for a further heat treatment at 800 °C for 12 hours. For eight of the compositions the first two cycles of synthesis failed to yield a single-phase product, a third cycle was attempted at a higher temperature of 900°C for 72 hours in each case, but this still do not produce the target phase.



The metal oxides Sc_2O_3 , In_2O_3 , Y_2O_3 , La_2O_3 , Cu_2O (anhydrous) and Ag_2O were purchased from Sigma-Aldrich with 99.9+% purity and used as provided. BaS, BaSe and BaO were all synthesized prior to use as precursors, using the following methods. BaS was synthesized by the decomposition and sulfurization of $BaCO_3$ (Alfa Aesar 99.99%) with CS_2 vapour (Fisher, 99.8%) transported under a flow of argon (BOC Pureshield), at 900 °C for 8 hours.¹⁴ BaO was synthesized by decomposition of $BaCO_3$ under dynamic vacuum at 1000 °C with a dwell time of 14 hours. BaSe was produced from the reduction of $BaSeO_4$ under a 5% H_2 in N_2 atmosphere (BOC) at 500 °C for 4 hours. The $BaSeO_4$ precursor for this reaction was formed by precipitation from aqueous solutions of Na_2SeO_4 (Sigma-Aldrich, BioXtra) and $Ba(NO_3)_2$ (Sigma-Aldrich, 99%), over ice. The precipitated $BaSeO_4$ was then filtered and dried in air at 70 °C. X-ray diffraction was used to confirm the purity of these in-house synthesised precursors, to within the sensitivity limit of the technique. All precursors and products were stored in a nitrogen filled glove box.

Characterisation. A Bruker D2 diffractometer equipped with a copper K_α X-ray source and Lynx Eye detector was used to collect powder X-ray diffraction patterns, in the range of $10^\circ < 2\theta < 100^\circ$, with a 0.02° step size and a scan time of 3 hours. Collected diffraction patterns were analysed using Rietveld refinement carried out with the GSAS-II software package.¹⁵ Spectroscopic data were recorded using a Perkin Elmer Lambda 750S instrument, equipped with an integrating sphere. Spectra were measured across the range of 300 nm to 2500 nm, and used to determined sample band gaps with the method outlined by Poeppelmeier.¹⁶

Preliminary photocatalytic studies were conducted on a sample of $\text{Ba}_3\text{Sc}_2\text{O}_2\text{Ag}_2\text{Se}_2$, using the dichloroindophenol (DCIP) dye degradation test.¹⁷ A co-catalyst of cobalt oxide was deposited on the oxyselenide powder using a method modified from the literature.¹⁸ In brief, 25 mg of $\text{Ba}_3\text{Sc}_2\text{O}_2\text{Ag}_2\text{Se}_2$ was placed in sample vial to which was added 10 ml of a 4.24 mol dm^{-3} $\text{Co}(\text{NO}_3)_2 \cdot 6\text{H}_2\text{O}$ (Sigma Aldrich, 98+%) solution in acetone. The acetone was allowed to evaporate overnight, and the cobalt nitrate impregnated powder sample was transferred to an alumina boat which was placed in a tube furnace. The sample was heated to $700 \text{ }^\circ\text{C}$ under a flow of ammonia, and annealed for 1 hour. The sample was cooled under ammonia flow, and then heated to 200°C for 1 hour under air exposure. This process initially reduced to cobalt nitrate to metallic cobalt, and then partially oxidised to the desired cobalt oxide co-catalyst, with an approximate loading of 2% cobalt by mass.

The $\text{CoO}_x@ \text{Ba}_3\text{Sc}_2\text{O}_2\text{Ag}_2\text{Se}_2$ powder was assessed for photocatalytic activity by taking a 10 mg sample in a sample vial and adding 5 ml of a $6.44 \times 10^{-5} \text{ M}$ DCIP dye and $2.28 \times 10^{-3} \text{ M}$ glycerol solution. The test was conducted by placing a crown stirrer in the vial to disperse the powder, and exposing the sample vial to a 5-sun solar simulator (LS0104 150 W Xenon lamp) equipped with a UV filter. At 60 min intervals, for 180 mins, an aliquot was taken out of the vial, and then centrifuged to separate the dye from the powder. The visible light absorption spectrum of the dye solution was collected in the range of 300 nm to 800 nm using a Perkin Elmer lambda 750S spectrometer. The solution and powder were recombined, and the aliquot returned to the sample vial prior to continued light exposure. Changes in dye concentration caused by photocatalytic degradation were determined using the Beer-Lambert law relationship between absorption and concentration of the dye. Control tests were conducted using dye and glycerol solution under solar simulator illumination without the catalyst present, and the solution with and without catalyst stirred in the dark.

Room temperature conductivity measurements were carried out on a sample of $\text{Ba}_3\text{Sc}_2\text{O}_2\text{Cu}_2\text{Se}_2$. The compound was pressed into a pellet using a 5 mm die under 2 tons of pressure. The pellet was then annealed in an alumina crucible in a vacuum sealed silica tube at $800 \text{ }^\circ\text{C}$ for 12 hours. Wire contacts were attached to the annealed pellet (1.5 mm thick, 5 mm diameter) of $\text{Ba}_3\text{Sc}_2\text{O}_2\text{Cu}_2\text{Se}_2$ using silver epoxy, and four point resistance measurements collected using a Keithley DMM6500 multimeter.

Computational methodology. First-principles calculations were carried out using the Vienna Ab-initio Simulation Package (VASP).^{19, 20} Each of the modelled structures was relaxed using the PBEsol functional²¹ with a Hubbard-like U correction of 5.17 eV on Cu and Ag.¹ The Projector-Augmented Wave (PAW) method was used to describe interactions between the core and valence electrons.²² A plane-wave cut-off of 550 eV was used to avoid Pulay stress²³ and a Γ -centred mesh with a k-point

density of at least 70 \AA^3 was used to sample the Brillouin zone. Net forces on ions were reduced to less than 0.01 eV\AA^{-1} .

Competing phases for all $\text{Ba}_3\text{M}_2\text{O}_5\text{M}'_2\text{Ch}_2$ compounds were identified using the Materials Project API,²⁴ limiting the search to those compounds that appear in the ICSD and resulting in a total of 172 compounds as listed in Table S1. These competing phases were relaxed using the same calculation parameters described above, with a denser k -point mesh of at least 100 \AA^3 used for metallic phases. All PBEsol calculations were carried out using the Fireworks python package²⁵ and final values for energy above the convex hull of the compositional phase diagram (E_{hull}) were calculated using the Pymatgen python package.²⁶ Bond distances and angles were extracted automatically using the CrystalNN algorithm.²⁷

The screened hybrid exchange correlation functional, HSE06,^{28, 29} has been shown in previous work to accurately calculate the electronic structure of this family of compounds,³ and to calculate accurate band gaps across a wide range of materials,³⁰ so was used here to calculate band structures of the stable compounds. A plane-wave cutoff of 550 eV was used and a Γ -centred mesh with a k -point density of at least 70 \AA^3 was used to sample the Brillouin zone.

Band structures and optical absorption plots were produced using the Sumo python package.³¹ The optical absorption spectra were calculated using the real and imaginary parts of the dielectric constant calculated through a Kramers-Kronig transformation and a summation over the unoccupied bands, respectively, using a method by Adolph and co-workers.³² Within this formalism, intra-band and indirect absorptions are not accounted for and only direct valence to conduction band transitions are considered.³³ Charge carrier effective masses were calculated using the curvature and electronic band extrema:

$$\frac{1}{m_{ij}^*} = \frac{\delta^2 E(k)}{\delta k_i \delta k_j} \frac{1}{\hbar^2} \quad \text{Equation 2}$$

Where $E(k)$ is the energy eigenvalue of the band at k -point k .

Results and Discussion

We have investigated 32522 compositions of the type $\text{Ba}_3\text{M}_2\text{O}_5\text{M}'_2\text{Ch}_2$ where $M = \text{Sc, In Y or La}$; $\text{Ch} = \text{S or Se}$; and $M' = \text{Cu or Ag}$, and can report the successful formation of four novel layered oxychalcogenide phases: $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{Se}_2$, $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Ag}_2\text{Se}_2$, $\text{Ba}_3\text{In}_2\text{O}_5\text{Ag}_2\text{Se}_2$ and $\text{Ba}_3\text{Y}_2\text{O}_5\text{Cu}_2\text{Se}_2$ with a confirmed purity for each of at least 97% as determined by Rietveld refinement of powder XRD. These materials were annealed twice at $800 \text{ }^\circ\text{C}$ under vacuum but were found to be air stable once cooled to room temperature, with the exception of $\text{Ba}_3\text{Y}_2\text{O}_5\text{Cu}_2\text{Se}_2$ which decomposed after several days exposure to air.

Rietveld refinement. The powder X-ray diffraction patterns of the four novel materials were modelled using the Rietveld method with the structure of the previously reported $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{S}_2$ as a starting point,³ using appropriate ion substitutions to match the expected composition in each case. For each phase the lattice, atomic position, and isotropic displacement parameters were refined to optimise the structural model. The sample background was also refined, while the instrumental peak profile parameters were fixed with values derived from refinement of the diffraction pattern of a highly crystalline LaB_6 sample collected on the same diffractometer. To account for the effect of the sample on Bragg peak broadening, the uniaxial size and strain parameters were refined. Where impurity peaks were identified, variously BaSe , BaCO_3 and In_2O_3 , these were modelled using standard crystal structures identified from the Inorganic Crystal Structure Database (ICSD),³⁴⁻³⁶ with lattice, particle size, and phase fraction parameters refined.

Using this approach good fits to the powder diffraction patterns were found for the samples where the observed Bragg peaks could be assigned to the expected target phase, with wR_p values of less than 4.66 % for these four samples. The Rietveld refinement fits to the data are shown in figure 2. $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{Se}_2$ was found with 99.0% purity by mass, with the remaining Bragg peaks assigned to small amounts of BaSe and BaCO_3 . The sample of $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Ag}_2\text{Se}_2$ was 97.9% pure with only BaCO_3 as an impurity; $\text{Ba}_3\text{In}_2\text{O}_5\text{Ag}_2\text{Se}_2$ was found alongside 2.4 % BaCO_3 and 0.6% In_2O_3 ; finally, $\text{Ba}_3\text{Y}_2\text{O}_5\text{Cu}_2\text{Se}_2$ had no identifiable crystalline impurity. A summary of the key refinement fit and lattice parameters for these four samples can be seen in table 1.

	$\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{Se}_2$	$\text{Ba}_3\text{Sc}_2\text{O}_5\text{Ag}_2\text{Se}_2$	$\text{Ba}_3\text{In}_2\text{O}_5\text{Ag}_2\text{Se}_2$	$\text{Ba}_3\text{Y}_2\text{O}_5\text{Cu}_2\text{Se}_2$
Lattice parameter a / Å	4.18127(7)	4.21678(11)	4.25908(8)	4.3898(3)
Lattice parameter c / Å	27.7132(6)	28.6608(10)	28.8780(6)	27.474(2)
Volume / Å ³	484.51(2)	509.63(4)	523.84(3)	529.42(9)
Data Points	4443	4443	4443	4443
Reflections (main phase)	106	112	112	116
Parameters	37	34	35	46
Purity	99.0 %	97.9 %	97.0 %	100%
wR_p	3.52	3.92	4.43	4.66
RF^2	2.20	3.76	2.25	4.90
χ^2	1.80	1.64	1.68	1.41
Colour	Pale Brown	Yellow-green	Black	Brown
Ba1 (0.5, 0.5, z)	0	0	0	0
Ba2 (0.5, 0.5, z)	0.1424(1)	0.1367(1)	0.1384(1)	0.1462(4)
M; (0, 0, z)	Sc; z=0.0718(3)	Sc; z=0.0695(3)	In; z=0.0710(1)	Y; z=0.0766(6)
O1 (0.5, 0, z)	0.0814(5)	0.0783(5)	0.0804(4)	0.089(2)
O2 (0, 0, z)	0	0	0	0
M'; (0.5, 0, z)	Cu; z=0.25	Ag; z=0.25	Ag; z=0.25	Cu; z=0.25
Se (0, 0, z)	0.198(1)	0.1885(2)	0.1892(1)	0.2002(7)

Table 1. Summary Rietveld refinement for novel $\text{Ba}_3\text{M}_2\text{O}_5\text{M}'_2\text{Ch}_2$. All structures were refined in $I4/mmm$, and errors are two standard deviations. Full site refinement results and CIF files are available in the ESI.

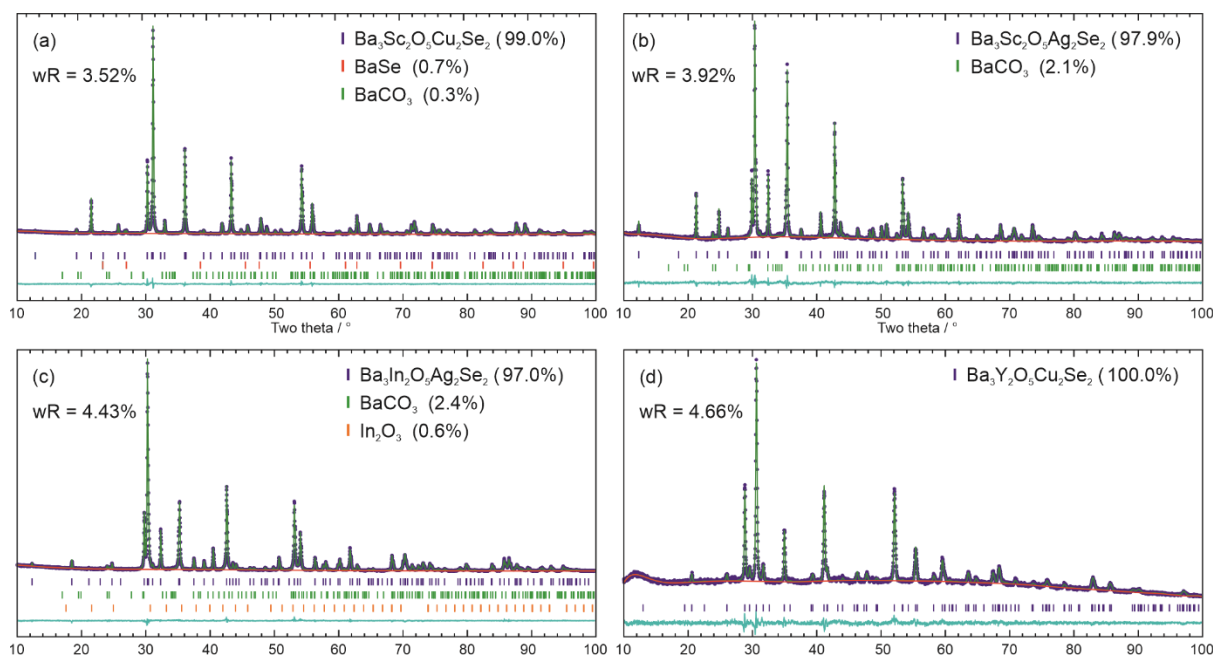


Figure 2. Rietveld refinement fits of the $I4/mmm$ structure to diffraction data, with purity by mass and wRp fit values given for each data set: a) $Ba_3Sc_2O_5Cu_2Se_2$; b) $Ba_3Sc_2O_5Ag_2Se_2$; c) $Ba_3In_2O_5Ag_2Se_2$; d) $Ba_3Y_2O_5Cu_2Se_2$. In each plot the diffraction data is shown in blue, the model in in green and the background in red. Below the data are tick marks indicating the positions of the peaks, and a cyan difference curve.

In addition to the four novel $Ba_3M_2O_5M'_2Ch_2$ compounds discussed above, there are a further four that have been previously reported: $Ba_3Sc_2O_5Cu_2Se_2$, $Ba_3InO_5Cu_2S_2$, $Ba_3In_2O_5Cu_2Se_2$, and $Ba_3Y_2O_5Ag_2Se_2$, although for the final example only the lattice parameters have been provided, with no further structural details^{3, 4, 9} These stable layered oxychalcogenides provide a suite of homologous materials with which to compare our novel compounds, in the discussion below. We did attempt to repeat the synthesis of $Ba_3Y_2O_5Ag_2Se_2$ for this work but found the material to be extremely air sensitive and were unable to collect diffraction data of sufficient quality to refine the atomic positions in order to provide a detailed structural analysis, however we are able to confirm the reported lattice parameters (ESI Figure S1). We found that the related yttrium containing copper selenide, $Ba_3Y_2O_5Cu_2Se_2$, is also air sensitive, but the decomposition is much slower, which allowed us to collect diffraction data of sufficient quality for Rietveld refinement, as described above.

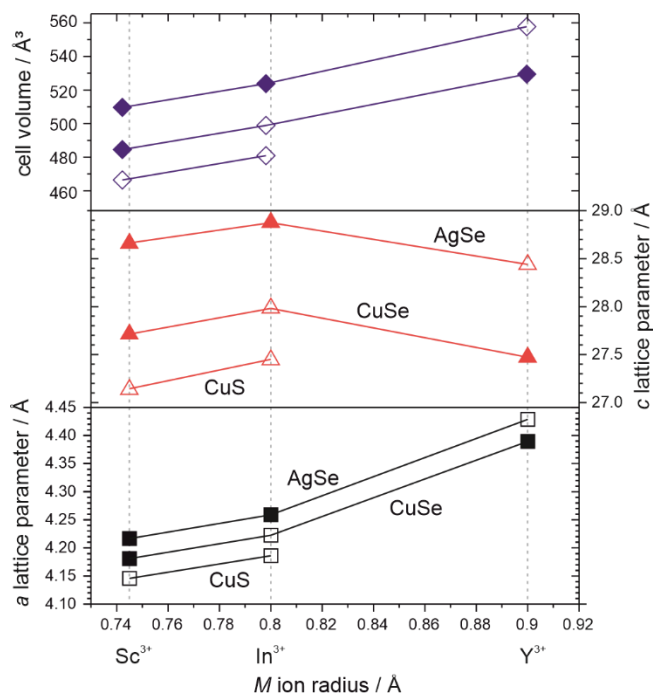


Figure 3 Plot of the lattice parameters for the $I4/mmm$ structured $Ba_3M_2O_5M'_2Ch_2$ phase plotted against the ionic radius of the M^{3+} ion present in each sample. Guidelines indicate and connect the samples with the same heavy anion layer. The a parameter is shown in the lower graph with squares, and the c lattice parameter in the middle graph with triangles. The top graph depicts the cell volume versus M ionic radii. Open symbols indicate previously reported materials, from references 3, 4 and 9, closed symbols represent novel materials reported in this paper.

Lattice parameter trends. Plots of the cell volume and a and c lattice parameters are shown in figure 3, for the four novel and four previously reported layered oxychalcogenides containing the $[Ba_3M_2O_5]^{2+}$ layer, as a function of the ionic radius of the M^{3+} ion. For a given oxide block, increasing the size of the ions in chalcogenide layer also leads to an increase in both a and c lattice parameter, as would be expected. The magnitude of the change between chalcogenide layers is surprisingly consistent independent of the oxide block in question, an increase of 0.9% in a and 2.0% in c with substitution of copper sulfide to copper selenide and 0.9% in a and 3.3% in c with substitution of copper selenide to silver sulfide. Considering the trends for a given chalcogenide layer, we observe the expected increase in the a lattice parameter with increasing M^{3+} ion radius. For example, for the copper selenides, the a lattice parameters are 4.18 Å, 4.22 Å and 4.39 Å for samples containing Sc^{3+} , In^{3+} and Y^{3+} respectively. In contrast for changes in the c lattice parameter something more unusual is observed. There is an increase with the substitution of indium for scandium, but substitution for the larger yttrium ion leads to a decrease in the c lattice parameter. Overall however, the trends in cell volume are fully consistent with increasing ion size leading to increased cell volume for substitution in either the oxide or chalcogenide layers. Therefore, the unexpected decrease in c lattice parameter in $Ba_3Y_2O_5Cu_2Se_2$ and $Ba_3Y_2O_5Ag_2Se_2$ is compensated for by the greater increase in the a lattice parameter in each case. To fully explain these trends we must consider the structural changes within each layer.

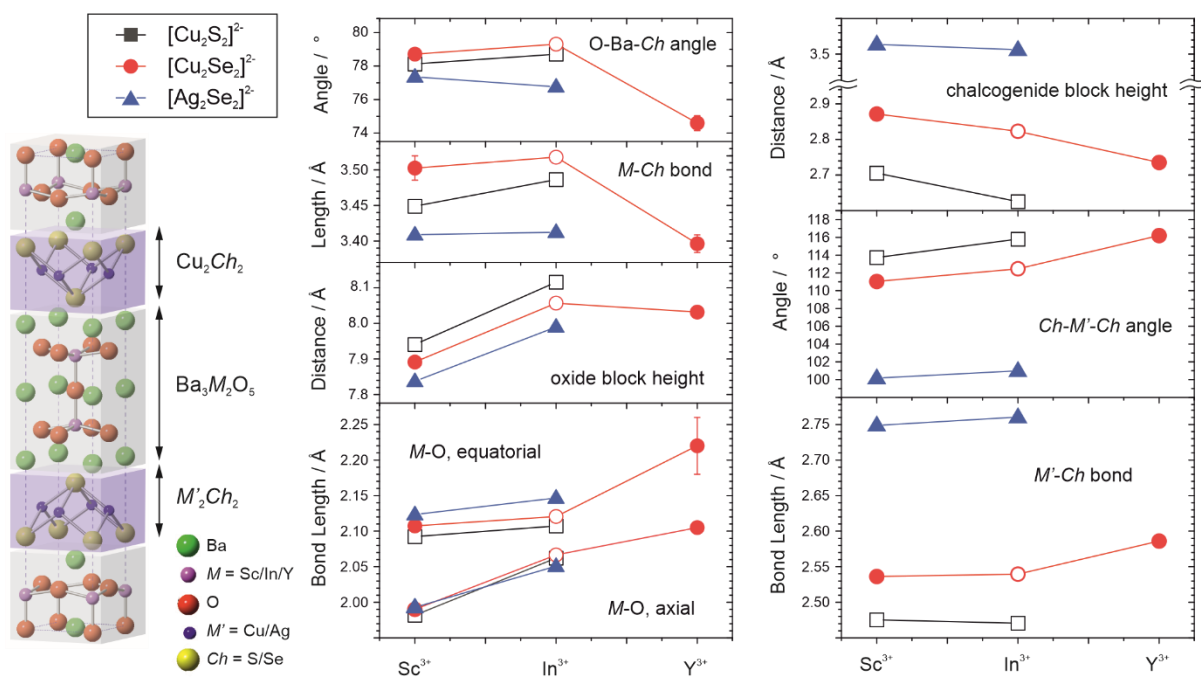


Figure 4. Left: Schematic diagram of the unit cell of the $Ba_3M_2O_5M'_2Ch_2$; ($M = Sc, In, Y$), ($M' = Cu, Ag$) and ($Ch = S, Se$). Centre and Right: Plots of the key angles, bond lengths and distances within the structure for the oxide and chalcogenide blocks. Values plotted as a function of the M ion in the oxide block, with chalcogenide layer distinguished by black squares for $[Cu_2S_2]^{2-}$, red circles for $[Cu_2Se_2]^{2-}$, and blue triangles for $[Ag_2Se_2]^{2-}$. Filled symbols are for new materials reported here, empty symbols are from prior literature, references 3,4 and 9. The lines shown connect samples with the same chalcogenide layer as a guide to the eye. Where they are not shown, the error bars are smaller than the symbols used.

Structural details. Key bond angles, lengths and structural distances are shown in figure 4, and tabulated in Table S2 of the ESI. These can be used to explain the observed changes and trends in the lattice parameters. We observe that for a given oxide block there is an expansion in both the a and c lattice parameter as a function of the heavy anion layer. This is clearly driven by the increasing length of the chalcogenide bond in order from Cu-S to Cu-Se to Ag-Se, due to the increasing ion sizes. The expansion in the a lattice parameter is partially constrained by the static oxide layer, so the longer chalcogenide bond is predominantly accommodated by the flexibility of chalcogenide layer,³ with a smaller bond angle and greater chalcogenide block height. This can be observed by consideration of the three samples with the $[Ba_3Sc_2O_5]^{2+}$ layer; with copper sulfide the S-Cu-S bond angle is 114° and the chalcogenide block height is 2.71 \AA . The angle tightens to 111° with a block height of 2.87 \AA for the copper selenide, the sequence ending with an angle of 100° and block height of 3.51 \AA , for the much longer silver selenide bond. The height of the oxide block, as measured by the Ba-Ba distance, remains relatively constant, varying by only about 0.01 \AA from the copper sulfide to the silver selenide as the apical M-O bond length which controls this distance is almost independent of the chalcogenide layer.

For a given chalcogenide layer the expansion in a lattice parameter with the replacement of Sc by In is of course driven by the increased size of the M^{3+} ion, which can be seen in the observed increase in the M-O bond length and especially the axial bond lengths, with an increase of 0.08 \AA . This leads

to the expansion of the oxide block height seen in figure 4 in the increase in the Ba-Ba distance. The response of the chalcogenide layer is only a limited change in the chalcogenide bond length, with the flexibility of the layer leading to an increase of the *cis*-bond angle instead, and a correspondingly reduced chalcogenide layer block height. For example, comparing $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Ag}_2\text{Se}_2$ to $\text{Ba}_3\text{In}_2\text{O}_5\text{Ag}_2\text{Se}_2$ the silver selenide bond angle increases by 1° and the heavy layer block height decreases by 0.015 \AA . Despite this decrease in the height of the chalcogenide layer with exchange of scandium for indium in each of the chalcogenide series, the much larger increase in the height of the oxide layer predominates and accounts for the observed increase in *c*-lattice parameter.

These trends in bond length and angle changes in the oxide and chalcogenide blocks extend to $\text{Ba}_3\text{Y}_2\text{O}_5\text{Cu}_2\text{Se}_2$, yet despite this we observe the anomalous decrease in the *c*-lattice parameter. This can be rationalised as decrease in the cell height comes from a significant drop in the interlayer spacing controlled by the square cuboid environment of the interlayer barium. The significant expansion in the *a* lattice parameter, when comparing $\text{Ba}_3\text{In}_2\text{O}_5\text{Cu}_2\text{Se}_2$ to $\text{Ba}_3\text{Y}_2\text{O}_5\text{Cu}_2\text{Se}_2$, caused by the much larger yttrium ion results in a flattening of the cuboid barium environment, as seen in the sharp decrease in the O-Ba-Ch angle from 79.3° to 74.6° , and a significant decrease in the interlayer spacing, as measured by the *M-Ch* distance which spans this environment and accounts for a 0.49 \AA decrease across the unit cell. This can be thought of as the chalcogenide and oxide layers expanding in the basal direction around the inter-layer barium and towards each other in the 001 direction, as the barium ion is no longer the ideal size for the site when compared to the pairings with smaller ions.

DFT calculations. DFT calculations were carried out for all of the 16 proposed $\text{Ba}_3\text{M}_2\text{O}_5\text{M}'_2\text{Ch}_2$ compositions, and their stability compared to binary and ternary competing phases. Full details of the results of these calculations can be found in Table S3. Eight of these were found to have an energy above the convex hull (E_{hull}) of zero, indicating that they are stable compared to the competing phases. These eight stable compounds matched with the four previously reported samples, and the four novel compounds prepared here. The eight compounds determined to be unstable with respect to the competing phases were those that also could not be experimentally prepared, which will be discussed in more detail below. Overall, it highlights for these layered oxychalcogenide systems, that energy above the convex hull is an excellent predictor for experimental stability.

The calculations also allowed the structures to be predicted, including the material for which we could not refine a structure, $\text{Ba}_3\text{Y}_2\text{O}_5\text{Ag}_2\text{Se}_2$. There was a good match between the structures derived from Rietveld modelling of experimental data and the structures derived from computational methods, with the lattice parameters of the models matching experimental results within 1% for all samples. Comparing the calculated bonds and angles, the observed differences between the two

models were: barium-barium distance, less than 0.4%, barium to anion bonds less than 2%, M-O bonds <1.5% and O-M-O angle <2% ($M = \text{Sc, In, Y}$). Previous work has shown that the PBEsol functional slightly overestimates the chalcogenide bond angle compared to experiment, and this is reflected again here with both copper and silver chalcogenide angle. The computational model overpredicts the Ch-M'-Ch angle by up to 3.5%, and underpredicts the bond length by 3%.

Overall, the accurate match between the DFT calculations and the empirically derived structural models provides confidence that we can reliably interpret the model derived for $\text{Ba}_3\text{Y}_2\text{O}_5\text{Ag}_2\text{Se}_2$ for which it was not possible to collect Rietveld quality data. For $\text{Ba}_3\text{Y}_2\text{O}_5\text{Ag}_2\text{Se}_2$, the DFT structural model indicates a continuation of the structural trends observed in the rest of the series. The reduction in the length of c parameter compared to $\text{Ba}_3\text{In}_2\text{O}_5\text{Ag}_2\text{Se}_2$, which we can observe experimentally, is due to a significant decrease in the inter-layer spacing, as the expansion in the a lattice parameter driven by the larger yttrium ion forces a flattening of the square cuboid environment of the inter layer barium. There is almost no expansion in the oxide block in the 001 direction despite the larger yttrium cation, and only the expected slight decrease in the chalcogenide block height.

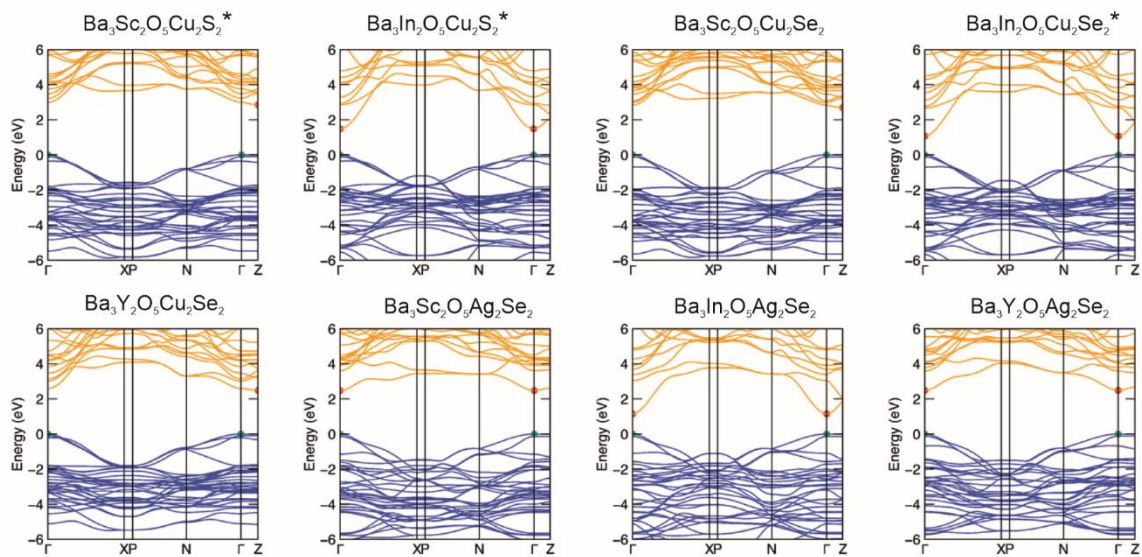


Figure 5. Electronic band structures of the eight thermodynamically stable $\text{Ba}_3\text{M}_2\text{O}_5\text{M}'_2\text{Ch}_2$ compounds calculated using the HSE06 DFT functional. Red and green dots mark the conduction band minimum (CBM) and valence band maximum (VBM), respectively. Compositions marked with an asterisk have been published previously.³⁻⁴

Electronic structure and optical properties. The full electronic band structures of the eight stable compounds are shown in Figure 5 and these are used to calculate the light hole effective masses (m_{hole}^*). Three of these band structures have been previously reported ($\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{S}_2$, $\text{Ba}_3\text{In}_2\text{O}_5\text{Cu}_2\text{S}_2$ and $\text{Ba}_3\text{In}_2\text{O}_5\text{Cu}_2\text{Se}_2$) and are reproduced here for completeness, marked with an asterisk.^{3, 4} The values of m_{hole}^* in the $[\text{Cu}_2\text{Ch}_2]^{2-} / [\text{Ag}_2\text{Se}_2]^{2-}$ planes are found at $\Gamma - \text{X}$ and $\Gamma - \text{N}$ and

are relatively low. The values for each sample are reported in Table 2, but across all samples the intraplane hole masses are found in the range $0.37 m_e$ to $0.65 m_e$, with lower values for selenide containing materials and higher values for the sulfide compounds. Overall the hole masses are comparable to the values predicted for $\text{Sr}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{S}_2$ of $0.35 m_e$ to $0.45 m_e$,¹ and in which high hole mobility has been experimentally verified. The Γ - Z reciprocal space direction corresponds to hole transport in the interplanar direction, and the modelled band structures show very flat bands, indicating much higher hole masses and limited mobility, as expected.

The band gaps of the novel materials were experimentally determined from analysis of the diffuse reflection spectra, using the method recently outlined by Poepelmeier, as suitable for crystalline, non-degenerate semiconductors.¹⁶ In brief, the Kubelka-Munk function was used to estimate the sample absorption from the reflectivity,³⁷ and then a plot of the square of the absorption against the photon energy was used to extrapolate a tangent from the point of inflection to determine the band gap of the sample (Figure 6). This was carried out for three of the novel materials, $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{Se}_2$ (band gap of 3.1 eV), $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Ag}_2\text{Se}_2$ (2.6 eV), $\text{Ba}_3\text{In}_2\text{O}_5\text{Ag}_2\text{Se}_2$ (1.4 eV). These band gaps values are given in table 2, alongside those previously reported for $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{S}_2$, $\text{Ba}_3\text{In}_2\text{O}_5\text{Cu}_2\text{S}_2$ and $\text{Ba}_3\text{In}_2\text{O}_5\text{Cu}_2\text{Se}_2$ and the values determined computationally from calculated optical absorption plots (Figure S2). For the yttrium containing samples experimental measurements could not be made due to their air sensitivity, so only the modelled band gaps are reported. Overall, there is good agreement between the experimental and calculated band gaps, as would be expected based on what we have shown previously for this family of materials.³

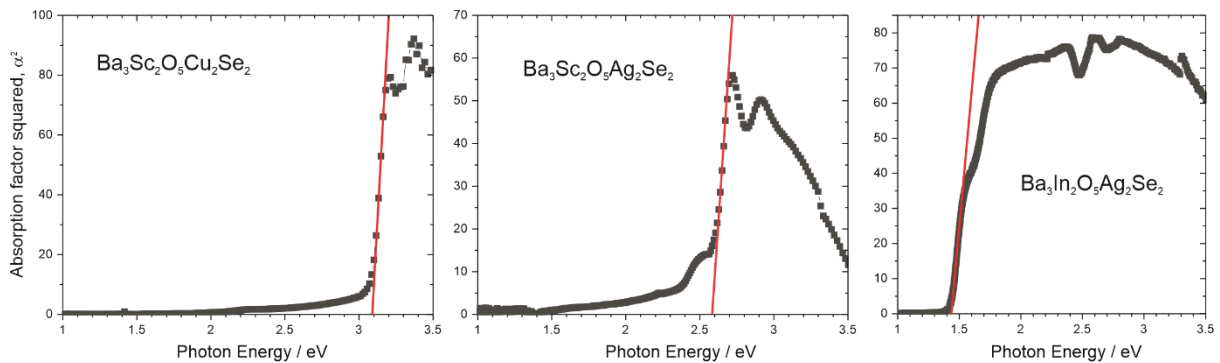


Figure 6. Plots of α^2 against photon energy for novel compositions, $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{Se}_2$, $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Ag}_2\text{Se}_2$, and $\text{Ba}_3\text{In}_2\text{O}_5\text{Ag}_2\text{Se}_2$, to allow band gaps to be determined from tangents shown in red. Absorption co-efficient determined using the Kubelka-Munk transformation. Spectra for yttrium containing samples could not be obtained due to air sensitivity.

The trends in the band gaps observed for this series of compounds can be explained by considering the composition of the band edges derived from the electronic structure modelling. For all of the compounds, the valence band maximum (VBM) is comprised predominantly of the filled chalcogenide p orbitals, while the conduction band minimum (CBM) is predominantly composed of the empty coinage metal s states, except for the indium containing samples with the $[\text{Ba}_3\text{In}_2\text{O}_5]^{2+}$ block, where

the In 5s states dominate then CBM. Ignoring the for the moment indium containing samples, this means that in the majority of the samples the size of the band gap is dependant only on the composition of the chalcogenide layer. We would expect sulfides to have larger band gaps than selenides, as the more electronegative sulfur lowers the VBM, while compounds with copper in the heavy layer would have a larger band gap than silver containing samples, as the more electronegative silver lowers the position of the CBM.

This explains why $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{S}_2$ has the largest band gap (3.24 eV, modelled value), due to the electronegative sulphur lowering the VBM, and the relatively electropositive copper raising the CBM. As both $\text{Ba}_3\text{Y}_2\text{O}_5\text{Cu}_2\text{Se}_2$ and $\text{Ba}_3\text{S}_2\text{O}_5\text{Cu}_2\text{Se}_2$ share the copper selenide heavy layer they have similar modelled band gaps (3.04 eV and 2.95 eV), due the VBM and CBM being composed of the same orbitals, but smaller than $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{S}_2$ due to the contribution of the more electropositive selenium to the VBM. The silver selenides; $\text{Ba}_3\text{Y}_2\text{O}_5\text{Ag}_2\text{Se}_2$ and $\text{Ba}_3\text{S}_2\text{O}_5\text{Ag}_2\text{Se}_2$ both have smaller band gaps of 2.63 eV and 2.60 eV, due to presence of the lower lying silver 5s states. The indium containing compounds have much smaller band gaps, as indium 5s states are much lower in energy than either copper or silver ns states giving band gap energies of 1.84 eV, 1.58 eV and 1.48 eV for the copper sulfide, silver selenide and copper selenide, respectively. The small differences observed in the modelled band gaps for the pairs $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{Se}_2$ and $\text{Ba}_3\text{Y}_2\text{O}_5\text{Cu}_2\text{Se}_2$ (2.95 eV to 3.04 eV); $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{Se}_2$ and $\text{Ba}_3\text{Y}_2\text{O}_5\text{Cu}_2\text{Se}_2$ (2.60 eV to 2.63 eV); and $\text{Ba}_3\text{In}_2\text{O}_5\text{Cu}_2\text{Se}_2$ and $\text{Ba}_3\text{In}_2\text{O}_5\text{Ag}_2\text{Se}_2$ (1.48 eV to 1.58 eV), despite each pair having identical band edge compositions, is due to a secondary effect where an increase in the basal lattice parameter reduces overlap and decreases the dispersion in the bands leading to the slight increase in band gap.⁸

	Band Gap / eV	HSE06 optical band gap / eV	Light hole mass / m_e	VBM composition	CBM composition
$\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{S}_2^*$	3.27*	3.24	0.6-0.64	S 2p	Ba 5d, Cu 4s
$\text{Ba}_3\text{Y}_2\text{O}_5\text{Cu}_2\text{Se}_2$	**	3.04	0.46-0.5	Se 3p	Ba 5d, Cu 4s
$\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{Se}_2$	3.09	2.95	0.45	Se 3p	Ba 5d, Cu 4s
$\text{Ba}_3\text{Y}_2\text{O}_5\text{Ag}_2\text{Se}_2^*$	**	2.63	0.46-0.48	Se 3p	Ag 5s
$\text{Ba}_3\text{Sc}_2\text{O}_5\text{Ag}_2\text{Se}_2$	2.58	2.60	0.44-0.56	Se 3p	Ag 5s
$\text{Ba}_3\text{In}_2\text{O}_5\text{Cu}_2\text{S}_2^*$	1.77*	1.84	0.54-0.56	S 2p	In 5s
$\text{Ba}_3\text{In}_2\text{O}_5\text{Ag}_2\text{Se}_2$	1.44	1.58	0.37-0.56	Se 3p	In 5s
$\text{Ba}_3\text{In}_2\text{O}_5\text{Cu}_2\text{Se}_2^*$	1.32*	1.48	0.40-0.49	Se 3p	In 5s

Table 2. Calculated and experimental band gaps, with calculated light hole mass ranges. The orbitals comprising the VBM and CBM are also listed. Samples are listed in order of decreasing band gap size. *Previously reported. **Uncertainty due to sample air sensitivity. Light hole effective masses for the newly reported compounds are broken down further by reciprocal space direction in Table S5

From the novel compounds reported in this work we can conclude from the electronic structure data that $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{Se}_2$ is of most interest as a possible p-type transparent conductor. It has a calculated hole mobility equivalent to $\text{Sr}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{S}_2$, and a sufficient large band gap to prevent visible light absorption and is air stable. We can also conclude that $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Ag}_2\text{Se}_2$ might be a

functional visible light photocatalyst, based on its reasonable transport properties and 2.6 eV band gap.

The visible light photocatalytic potential of $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Ag}_2\text{Se}_2$ was assessed using a dye degradation test, where a solution of dichloroindophenol (DCIP) dye undergoes reductive decolouration in the presence of glycerol as a sacrificial oxidant, enhanced by the photocatalyst. This is an effective and simple test to assess visible light photocatalysts.¹⁷ The sample of $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Ag}_2\text{Se}_2$ was loaded with a cobalt oxide co-catalyst to enhance its activity,¹⁸ and allow for measurements to be conducted in a 3 hour time window. A 5-sun solar simulator with a UV light filter was used as the light source. This found that 10 mg of $\text{CoO}_x@ \text{Ba}_3\text{Sc}_2\text{O}_5\text{Ag}_2\text{Se}_2$ in 5 ml of 6.44×10^{-5} M dye solution was able to degrade 15.1% of the dye during the three hour experiment. No degradation of the dye was observed without the catalyst present, or in the presence of the catalyst without the light source. This confirms that $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Ag}_2\text{Se}_2$ is a visible light photocatalyst, comparable to other layered oxychalcogenides tested using the same procedure, with a similar rate to $\text{Ba}_3\text{In}_2\text{O}_5\text{Cu}_2\text{S}_2$ (14.5% dye degradation in three hours), but lower than $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{SS}_2$ (27.0% degradation).⁴

Additionally, room temperature conductivity measurements were conducted on a pellet of $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{Se}_2$, which was found to have a density of 73% relative to the theoretical density derived from diffraction data. Four point probe measurements found that the pellet had a conductivity of $5.0(1) \times 10^{-5}$ S cm^{-1} , which is comparable to previous reports on other promising for pristine undoped layered oxychalcogenides such as LaOCuS (1×10^{-4} S cm^{-1}),¹⁰ and $\text{Sr}_2\text{GaO}_3\text{CuS}$ (2.2×10^{-4} S cm^{-1}),³⁸ although not as high as values reported for LaOCuSe (24 S cm^{-1}) or $\text{Sr}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{S}_2$ (2.8 S cm^{-1}).^{2, 39} However, it should also be considered that the value reported here for $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{Se}_2$ are for an annealed pellet, rather than a plasma sintered one.

Discussion of the unstable compositions. Above we discussed in detail the structural and electronic properties and relationships of the eight compounds that were found to be stable and could be synthesised from the 16 possible $\text{Ba}_3\text{M}_2\text{O}_5\text{M}'_2\text{Ch}_2$ compounds, where $M = \text{In, Sc, Y, Ga}$ and $M' = \text{Cu, Ag}$. It is valuable to consider, however, the factors which underlie why the remaining eight materials are not stable.

We have not been able to form any compound containing lanthanum, i.e those with a $[\text{Ba}_3\text{La}_2\text{O}_5]^{2+}$ layer. All Bragg peaks observed in the diffraction patterns of our attempts at these samples could be indexed to elemental or binary by-products, as summarised in table S4, with no indication of the expected peaks of the target phases. These syntheses were speculative, as there are no prior examples of lanthanum in the 5 coordinate M^{3+} ion environment in the 32522-structure type. The lanthanum ion, with an ionic radius of 1.03 Å, is considerably larger than the yttrium ion (0.90 Å) which is the largest ion found on the M site in the known examples of the structure type. We hypothesise that the limiting size for ions in the oxide block can be predicted based on the

Goldschmidt tolerance factor, t , originally derived for predicting the formability of the *perovskite* structure, using the relationship of the relative ion sizes r_A , r_B and r_O for the 12 coordinate cation site, the 6 coordinate cation site and the anion site, as shown in equation 3. Although not always a guarantee of stability, it is successful as a filter for unstable compositions in the *perovskites*.⁴⁰ A survey of all of the known 32522 structure types (and related 42622 structure) finds that these all have oxide layers with tolerance factors in the range of 0.9 to 1.0, which matches that observed for undistorted, cubic *perovskites*, implying that these oxychalcogenide structure types have a relative tight tolerance for the size of the ions. Calculating the tolerance factor for $[\text{Ba}_3\text{La}_2\text{O}_5]^{2+}$ give a value of 0.88, which falls outside of this stable range, and indicates that the barium ion is too small for the lanthanum ion. Perovskite type compounds can be made with tolerance factors less than 0.9, but these undergo distortion through polyhedral twisting, to reduce the size of the 12-coordinate A site. It is likely that such distortions are not possible in the 32522 structure due to the need for commensurate bonding to the chalcogenide layer.

$$t = \frac{r_A + r_O}{\sqrt{r_B + r_O}} \quad \text{Equation 3}$$

Oxide Layer	Tolerance factor, t
$[\text{Ba}_3\text{Sc}_2\text{O}_5]^{2+}$	0.99
$[\text{Ba}_3\text{In}_2\text{O}_5]^{2+}$	0.97
$[\text{Ba}_3\text{Y}_2\text{O}_5]^{2+}$	0.93
$[\text{Ba}_3\text{La}_2\text{O}_5]^{2+}$	0.88
Table 3. Tolerance factors for the oxide layers considered in this work	

The computational modelling for the lanthanum compounds also predicted them to be unstable with respect to decomposition. However, the relaxed structural models were produced assuming that the decomposition did not occur and, within the symmetry limitations, in order to accommodate the lanthanum ion these would have to have a lattice parameters of 4.49 Å for the copper sulfide, increasing to 4.56 Å for the silver selenide, values larger than any observed for a known layered oxychalcogenide. Inspection of the structural model for these found the central barium atom to be significantly under-bonded. This barium should be in a 12 co-ordinate geometry, however the length of the apical Y-O bond increases the size of the 12 co-ordinate site such that the barium is in effect only bonded to the equatorial oxygen ions providing an under-bonded pseudo-square planar geometry. Overall the computational modelling of the proposed lanthanum containing structures

confirm that these are unstable due to the large size of the lanthanum ion being incompatible with the size of the barium and also the majority of the chalcogenide layers.

We were also unable to experimentally synthesise any compound containing a silver sulfide layer, nor were any predicted to be stable from computational methods. At first this is surprising, given the ability to synthesis examples of all the other copper and silver chalcogenide layers. However, in each of the attempts at forming a silver selenide, the same by-products were observed, elemental silver and barium sulphate. Our hypothesis for this instability is that silver is too readily reduced by sulfide, with BaSO_4 acting as a thermodynamic sink. In contrast the silver selenides are stable because of the lower reduction potential of Se^{2-} compared to S^{2-} , and the consequent lower enthalpy of formation of BaSeO_4 . This also helps to explain the lack of prior examples of layered silver sulfides in the literature, where to our knowledge there are only two examples, these are LaOAgS ,⁴¹ and $\text{Sr}_3\text{Fe}_{2.5}\text{O}_5\text{Ag}_{1.5}\text{S}_2$; in the former there is no alkaline earth to form a sulphate and in the latter the composition is stabilised by partial substitution of silver for iron in the sulfide layer.⁴²

The final compound that could not be synthesized was $\text{Ba}_3\text{Y}_2\text{O}_5\text{Cu}_2\text{S}_2$. In our attempt at the synthesis of this we could not identify any of the expected peaks of the target phase in the diffraction pattern collected on the sample, which instead was found to contain Bragg peaks which could indexed to a mixture of Y_2O_3 , BaS , Cu , BaSO_4 and BaYO_4 . This inability to combine the $[\text{Ba}_3\text{Y}_2\text{O}_5]^{2+}$ layer with the $[\text{Cu}_2\text{S}_2]^{2-}$ layer can be rationalised based on the expected size. Yttrium is the largest of the three ions considered in the oxide block, while the $[\text{Cu}_2\text{S}_2]^{2-}$ layer contains the smallest pairing of ions for the chalcogenide layer, so it is likely that the $[\text{Ba}_3\text{Y}_2\text{O}_5]^{2+}$ is simply too large to be accommodated in structure with the copper sulfide layers. Although predicted to be unstable, it was still possible to computationally model and produce a relaxed structure for $\text{Ba}_3\text{Y}_2\text{O}_5\text{Cu}_2\text{S}_2$, which had predicted lattice parameters of 4.34 Å and 26.48 Å. The largest previously *a* lattice parameter for a layered oxychalcogenide containing copper sulfide layers is the value of 4.18 Å in $\text{Ba}_3\text{In}_2\text{O}_5\text{Cu}_2\text{S}_2$.⁴ In order to achieve this theoretical basal expansion to 4.34 Å the model requires an extreme stretching of the copper sulfide geometry, such that the S-Cu-S angle becomes 125°, even accounting for the tendency to over-predict the angle value, this is an extreme distortion from the ideal tetrahedral geometry. This would support the argument of size incompatibility as the reason for the inability to synthesis $\text{Ba}_3\text{Y}_2\text{O}_5\text{Cu}_2\text{S}_2$, and also suggest the possible upper size limit for inclusion of the copper sulfide layer is approximately 4.20 Å and certainly no larger than 4.35 Å.

Conclusions

Our investigation of the $\text{Ba}_3\text{M}_2\text{O}_5\text{M}'_2\text{Ch}_2$ compositions with coinage metal chalcogenide layers, and scandium, indium, yttrium and lanthanum oxide layers through both modelling and synthesis, has allowed us to identify four new compositions, $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{Se}_2$, $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Ag}_2\text{Se}_2$, $\text{Ba}_3\text{In}_2\text{O}_5\text{Ag}_2\text{Se}_2$, and $\text{Ba}_3\text{Y}_2\text{O}_5\text{Cu}_2\text{Se}_2$, and confirm that by targeting larger ions in the oxide layer we can promote the

formation of this 32522 structure. We have identified that the Goldschmidt tolerance factor can be used as a simple guide for predicting formability, and that this must lie within a range of 0.9 to 1.0 for ions in the oxide layer in order to produce a stable 32522 structure. Additionally, computational modelling is highly effective at predicting stability for this series of compounds. We have also provided an explanation for the instability of layered oxychalcogenides with silver sulfide layers, which is due to the favourable redox reaction between sulfide and silver ions. Finally, we have identified that $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Ag}_2\text{Se}_2$ has potential as visible light photocatalyst, based on its transport properties and band gap, while $\text{Ba}_3\text{Sc}_2\text{O}_5\text{Cu}_2\text{Se}_2$ is of interest as a possible p-type transparent conductor, and confirmed these with preliminary experiments.

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Supporting Information

Electronic Supplementary Information (ESI) available. Figure S1: Rietveld refinement of attempt at forming $\text{Ba}_3\text{Y}_2\text{O}_5\text{Ag}_2\text{Se}_2$. Figure S2: Calculated optical absorption data. Table S1: List of competing phases used in calculating energy above hull. Table S2: Selected band distances and angles from refined structural models. Table S3: Structural details from computational models. Table S4: Details of refinement of compounds which could not be synthesized. Table S5: Light hole masses for newly reported compounds.

All data supporting this study are openly available from the University of Southampton repository at <https://doi.org/10.5258/SOTON/D2122>

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